NSN 5962-01-283-9166

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View Online at https://aerobasegroup.com/nsn/5962-01-283-9166

Body Length:

1.290 inches

Body Width:

0.600 inches

Body Height:

0.180 inches

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

High performance and schottky and high speed and high reliability and multichip and low power and 3-state output and monolithic and

bipolar and electrostatic sensitive and hermetically sealed and programmable

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

14 input

Current Rating Per Characteristic:

185.00 milliamperes reverse current, dc absolute

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

5.0 volts power source

Capitance Rating Per Characteristic:

12.00 output picofarads

Time Rating Per Chacteristic:

55.00 nanoseconds access

Memory Device Type:

Prom

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

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